

# Pb ROHS COMPLIANT

# **TSM2312**

# 20V N-Channel MOSFET

### **SOT-23**



### Pin Definition:

- 1. Gate
- 2. Source
- 3. Drain

## **Key Parameter Performance**

Parameter		Value	Unit	
$V_{DS}$		20	V	
R <sub>DS(on)</sub> (max)	$V_{GS} = 4.5V$	33		
	$V_{GS} = 2.5V$	40	m	
	$V_{GS} = 1.8V$	51		
$Q_g$		11	nC	

## **Features**

Advance Trench Process Technology
High Density Cell Design for Ultra Low On-resistance

## **Application**

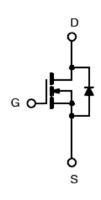
Load Switch PA Switch

## **Ordering Information**

Part No.	Package	Packing		
TSM2312CX RF	SOT-23	3kpcs / 7+Reel		
TSM2312CX RFG	SOT-23	3kpcs / 7+Reel		

**Note:** %+denotes for Halogen- and Antimony-free as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds

## **Block Diagram**



N-Channel MOSFET

## **Absolute Maximum Ratings** (T<sub>C</sub> = 25°C, unless otherwise noted)

Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		$V_{DS}$	20	V	
Gate-Source Voltage		$V_{GS}$	±8	V	
Continuous Drain Current		I <sub>D</sub>	4.9	Α	
Pulsed Drain Current (Note 1)		I <sub>DM</sub>	15	Α	
Continuous Source Current (Diode Conduction) (Note 2)		Is	1.0	Α	
Maximum Power Dissipation	Ta = 25°C	Б	0.75	W	
	Ta = 75°C	P <sub>D</sub>	0.48		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C	

## **Thermal Performance**

Parameter	Symbol	Limit	Unit	
Thermal Resistance Junction to Foot	R <sub>JF</sub>	75	°C/W	
Thermal Resistance Junction to Ambient	R <sub>JA</sub>	140	°C/W	



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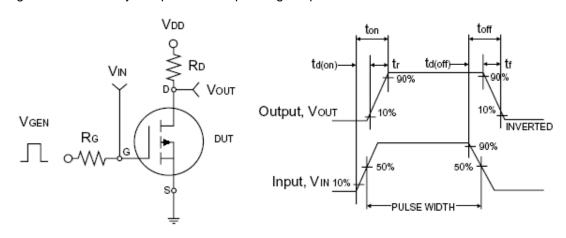


**Electrical Specifications** 

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Static <sup>(Note 3)</sup>						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250uA$	BV <sub>DSS</sub>	20			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250uA$	$V_{GS(TH)}$	0.45	0.65	1.0	V
Gate Body Leakage	$V_{GS} = \pm 8V, V_{DS} = 0V$	I <sub>GSS</sub>			±100	nA
Zero Gate Voltage Drain Current	$V_{DS} = 16V, V_{GS} = 0V$	I <sub>DSS</sub>			1.0	μΑ
On-State Drain Current	$V_{DS} = 10V, V_{GS} = 4.5V$	I <sub>D(ON)</sub>	15			Α
	$V_{GS} = 4.5V, I_D = 4.9A$			27	33	m
Drain-Source On-State Resistance	$V_{GS} = 2.5V, I_D = 4.4A$	R <sub>DS(ON)</sub>		33	40	
	$V_{GS} = 1.8V, I_D = 3.9A$			42	51	
Forward Transconductance	$V_{DS} = 15V, I_{D} = 5.0A$	<b>g</b> fs		40		S
Diode Forward Voltage	$I_S = 1.0A, V_{GS} = 0V$	$V_{SD}$		0.8	1.2	V
Dynamic <sup>(Note 4)</sup>						
Total Gate Charge		$Q_g$		11	14	
Gate-Source Charge	$V_{DS} = 10V, I_{D} = 5.0A,$	$Q_gs$		1.5		nC
Gate-Drain Charge	$V_{GS} = 4.5V$	$Q_{gd}$		2.1		
Input Capacitance	\/ 40\/ \/ 0\/	$C_{iss}$		500		
Output Capacitance	$V_{DS} = 10V, V_{GS} = 0V,$ f = 1.0MHz	C <sub>oss</sub>		300		pF
Reverse Transfer Capacitance		$C_{rss}$		140		
Switching <sup>(Note 5)</sup>						
Turn-On Delay Time	$V_{DD} = 10V, R_L = 10$ , $I_D = 1A, V_{GEN} = 4.5V,$ $R_G = 6$	t <sub>d(on)</sub>		15	25	
Turn-On Rise Time		t <sub>r</sub>		40	60	20
Turn-Off Delay Time		t <sub>d(off)</sub>		48	70	ns
Turn-Off Fall Time		t <sub>f</sub>		31	45	

#### Notes:

- 1. Pulse width limited by the maximum junction temperature
- 2. Surface Mounted on FR4 Board t m5 sec.
- 3. Pulse test: PW m300µs, duty cycle m2%
- 4. For DESIGN AID ONLY, not subject to production testing.
- 5. Switching time is essentially independent of operating temperature.



**Switching Test Circuit** 

Switchin Waveforms



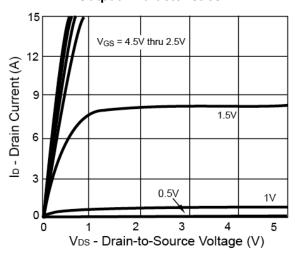
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## 20V N-Channel MOSFET

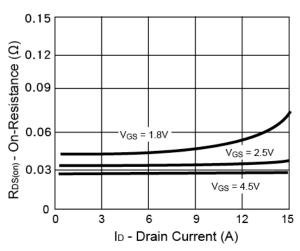
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### **Electrical Characteristics Curve**

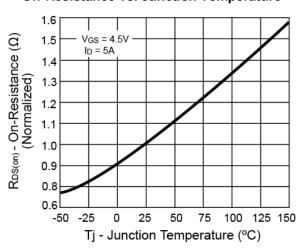
## **Output Characteristics**



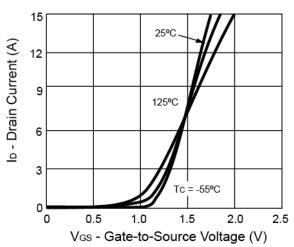
#### **On-Resistance vs. Drain Current**



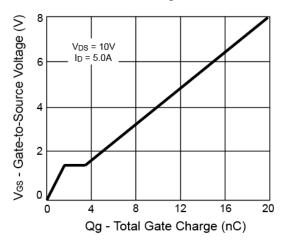
### On-Resistance vs. Junction Temperature



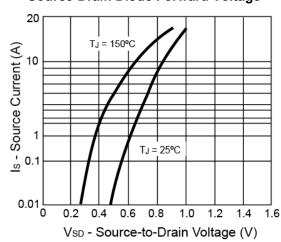
### **Transfer Characteristics**



## **Gate Charge**



### **Source-Drain Diode Forward Voltage**



Version: D15

3/6





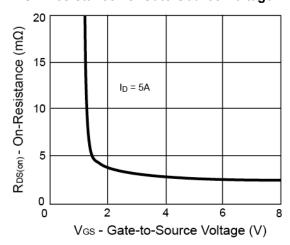
# **TSM2312**



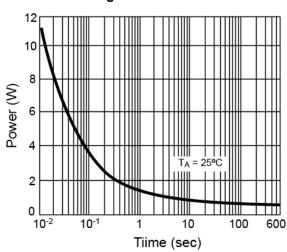


### **Electrical Characteristics Curve**

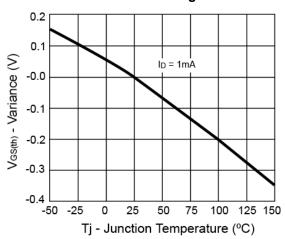
On-Resistance vs. Gate-Source Voltage



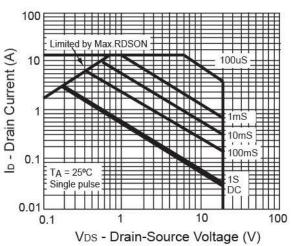
Single Pulse Power



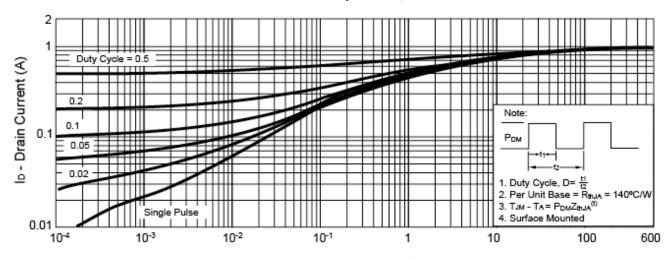
Threshold Voltage



**Safety Operation Area** 



Normalized Thermal Transient Impedance, Junction-to-Ambient

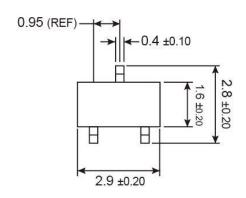


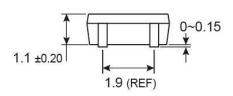
Square Wave Pulse Duration (sec)

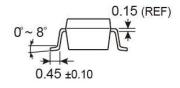




# **SOT-23 Mechanical Drawing**

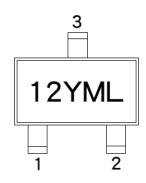






Unit: Millimeters

# **Marking Diagram**



12 = Device Code

Y = Year Code

M = Month Code

(**A**=Jan, **B**=Feb, **C**=Mar, **D**=Apl, **E**=May, **F**=Jun, **G**=Jul, **H**=Aug, **I**=Sep, **J**=Oct, **K**=Nov, **L**=Dec)

= Month Code for Halogen Free Product

(O=Jan, P=Feb, Q=Mar, R=Apl, S=May, T=Jun, U=Jul, V=Aug, W=Sep, X=Oct, Y=Nov, Z=Dec)

L = Lot Code



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